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**PATENT** 

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Pierre C. Fazan et al.

Examiner: Unknown

Serial No.:

Unknown

Group Art Unit: Unknown

Filed:

Herewith

Docket: 303.434US2

Title:

METHOD FOR FORMING A STORAGE CELL CAPACITOR COMPATIBLE

WITH HIGH DIELECTRIC CONSTANT MATERIALS

## SUPPLEMENTAL PRELIMINARY AMENDMENT

Assistant Commissioner for Patents Washington, D.C. 20231

After entering the Preliminary Amendment also enclosed herewith, please further amend the application as follows:

## IN THE SPECIFICATION

On page 2, line 1, before "This invention pertains", please insert the sentence, This application is a divisional of U.S Serial No. 08/572,392 filed 12/14/95 which is a continuation of U.S. Serial No. 08/390,336 filed 02/17/95.

## **IN THE CLAIMS**

Please cancel claims 58-68 without prejudice or disclaimer, and amend the remaining claims as follows:

- 28. (Amended) An electrode[,] comprising:
  - a) a first portion formed in an insulative layer;
  - b) a second portion overlying the first portion, wherein said insulative layer surrounds a sidewall of said second portion; and
  - c) a third portion overlying said second portion and at least a portion of said insulative layer, wherein said first portion and said second portion are different materials.
- 31. (Amended) An dynamic random access memory device[,] comprising: an electrode which comprises:
  - a) a first portion formed in an insulative layer;